

CMLDM3757

**SURFACE MOUNT SILICON  
N-CHANNEL AND P-CHANNEL  
ENHANCEMENT-MODE  
COMPLEMENTARY MOSFET**



**SOT-563 CASE**



www.centrasemi.com

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMLDM3757 consists of complementary silicon N-Channel and P-Channel enhancement-mode MOSFETs designed for high speed pulsed amplifier and driver applications. These MOSFETs offer very low  $r_{DS(ON)}$  and low threshold voltage.

**MARKING CODE: 3C7**

**FEATURES:**

- ESD protection up to 1800V (Human Body Model)
- 350mW power dissipation
- Very low  $r_{DS(ON)}$
- Low threshold voltage
- Logic level compatible
- Small, SOT-563 surface mount package

**APPLICATIONS:**

- Load/Power switches
- Power supply converter circuits
- Battery powered portable devices

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	8.0	V
Continuous Drain Current (Steady State)	$I_D$	540	430
Maximum Pulsed Drain Current ( $t_p=10\mu\text{s}$ )	$I_{DM}$	1500	750
Power Dissipation (Note 1)	$P_D$	350	mW
Power Dissipation (Note 2)	$P_D$	300	mW
Power Dissipation (Note 3)	$P_D$	150	mW
Operating and Storage Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Thermal Resistance (Note 1)	$\theta_{JA}$	357	$^\circ\text{C/W}$

SYMBOL	N-CH (Q1)		P-CH (Q2)		UNITS
$V_{DS}$		20			V
$V_{GS}$		8.0			V
$I_D$	540		430		mA
$I_{DM}$	1500		750		mA
$P_D$		350			mW
$P_D$		300			mW
$P_D$		150			mW
$T_J, T_{stg}$		-65 to +150			$^\circ\text{C}$
$\theta_{JA}$		357			$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$ )

SYMBOL	TEST CONDITIONS	N-CH (Q1)			P-CH (Q2)			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
$I_{GSSF}, I_{GSSR}$	$V_{GS}=4.5\text{V}, V_{DS}=0$	-	-	5.0	-	-	2.0	$\mu\text{A}$
$I_{DSS}$	$V_{DS}=16\text{V}, V_{GS}=0$	-	-	1.0	-	-	1.0	$\mu\text{A}$
$BV_{DSS}$	$V_{GS}=0, I_D=250\mu\text{A}$	20	-	-	20	-	-	V
$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.45	-	1.0	0.45	-	1.0	V
$V_{SD}$	$V_{GS}=0, I_S=350\text{mA}$	-	-	1.2	-	-	1.2	V
$r_{DS(ON)}$	$V_{GS}=4.5\text{V}, I_D=540\text{mA}$	-	0.35	0.55	-	-	-	$\Omega$
$r_{DS(ON)}$	$V_{GS}=4.5\text{V}, I_D=430\text{mA}$	-	-	-	-	0.4	0.9	$\Omega$
$r_{DS(ON)}$	$V_{GS}=2.5\text{V}, I_D=500\text{mA}$	-	0.5	0.7	-	-	-	$\Omega$
$r_{DS(ON)}$	$V_{GS}=2.5\text{V}, I_D=300\text{mA}$	-	-	-	-	0.55	1.2	$\Omega$
$r_{DS(ON)}$	$V_{GS}=1.8\text{V}, I_D=350\text{mA}$	-	0.7	0.9	-	-	-	$\Omega$
$r_{DS(ON)}$	$V_{GS}=1.8\text{V}, I_D=150\text{mA}$	-	-	-	-	0.75	2.0	$\Omega$

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm<sup>2</sup>  
 (2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm<sup>2</sup>  
 (3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm<sup>2</sup>

CMLDM3757

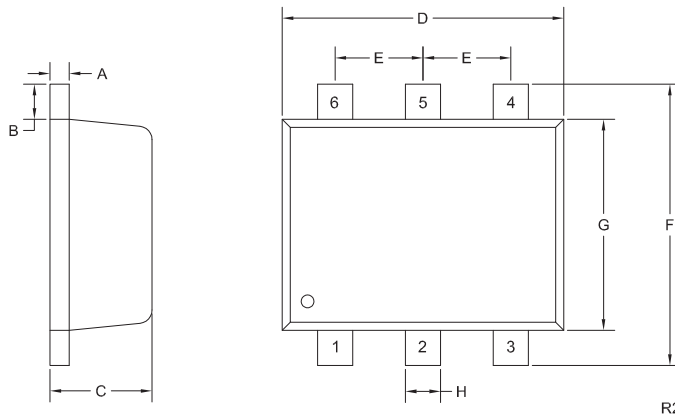
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**ELECTRICAL CHARACTERISTICS - Continued: ( $T_A=25^\circ\text{C}$ )**

SYMBOL	TEST CONDITIONS	N-CH (Q1)		P-CH (Q2)		UNITS
		TYP	MAX	TYP	MAX	
$C_{rss}$	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	-	20	-	20	pF
$C_{iss}$	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	-	150	-	175	pF
$C_{oss}$	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	-	25	-	30	pF
$Q_{g(\text{tot})}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=500\text{mA}$	1.58	-	-	-	nC
$Q_{g(\text{tot})}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=200\text{mA}$	-	-	1.2	-	nC
$Q_{gs}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=500\text{mA}$	0.17	-	-	-	nC
$Q_{gs}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=200\text{mA}$	-	-	0.24	-	nC
$Q_{gd}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=500\text{mA}$	0.24	-	-	-	nC
$Q_{gd}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=200\text{mA}$	-	-	0.36	-	nC
$t_{on}$	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=540\text{mA}, R_G=10\Omega$	10	-	-	-	ns
$t_{off}$	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=540\text{mA}, R_G=10\Omega$	25	-	-	-	ns
$t_{on}$	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=215\text{mA}, R_G=10\Omega$	-	-	38	-	ns
$t_{off}$	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=215\text{mA}, R_G=10\Omega$	-	-	48	-	ns

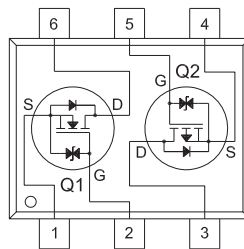
**SOT-563 CASE - MECHANICAL OUTLINE**



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.0027	0.007	0.07	0.18
B	0.008		0.20	
C	0.017	0.024	0.45	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.059	0.067	1.50	1.70
G	0.043	0.051	1.10	1.30
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R2)

**PIN CONFIGURATION**



**LEAD CODE:**

- 1) Source Q1
- 2) Gate Q1
- 3) Drain Q2
- 4) Source Q2
- 5) Gate Q2
- 6) Drain Q1

**MARKING CODE: 3C7**

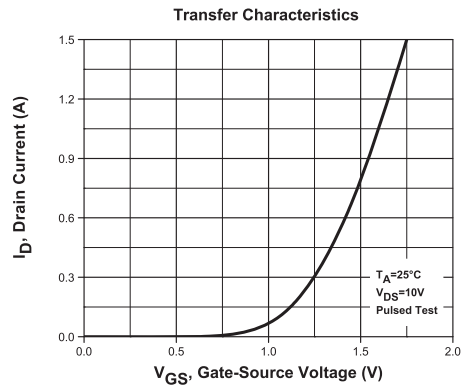
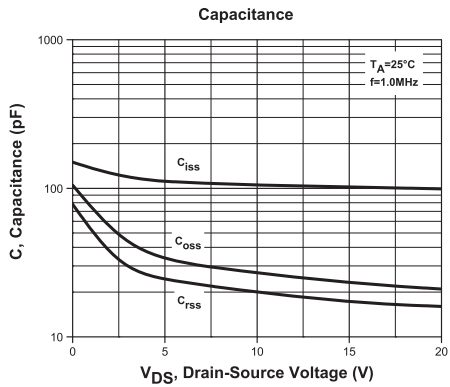
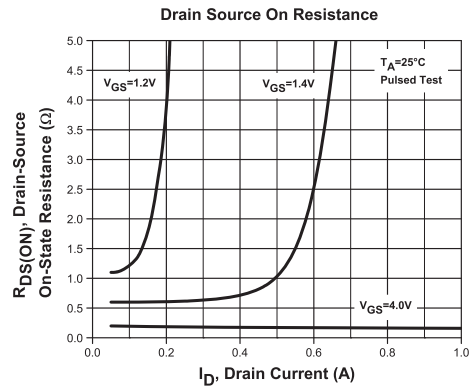
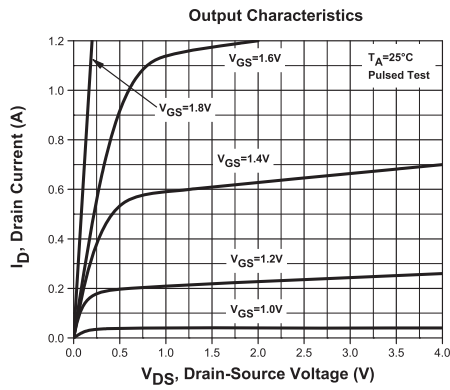
R6 (8-June 2015)

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### N-CHANNEL TYPICAL ELECTRICAL CHARACTERISTICS



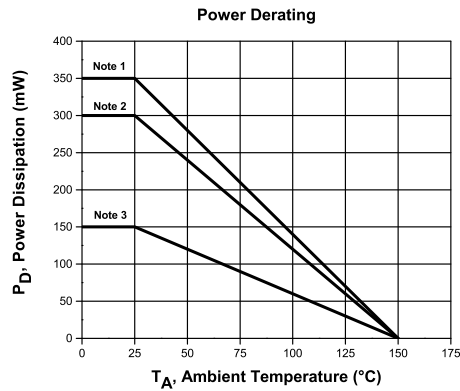
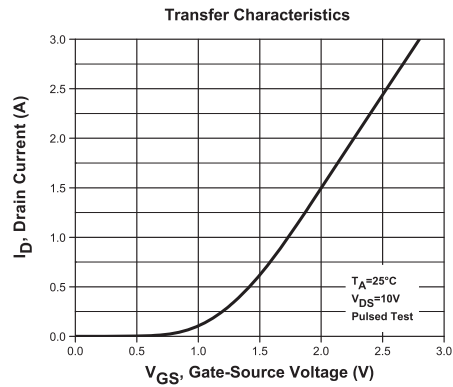
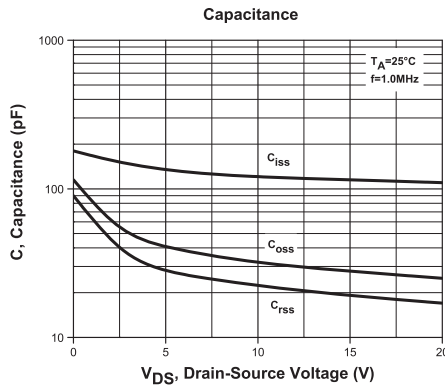
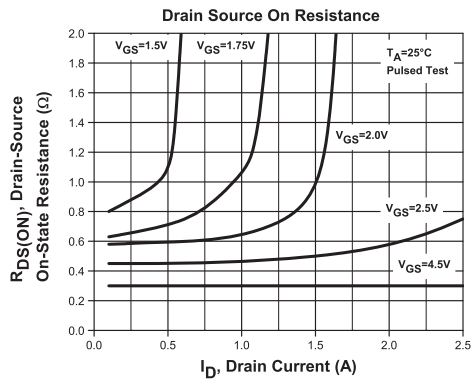
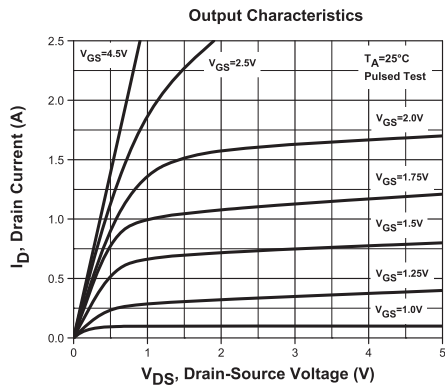
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### P-CHANNEL TYPICAL ELECTRICAL CHARACTERISTICS



R6 (8-June 2015)

## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

#### Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.  
145 Adams Avenue  
Hauppauge, NY 11788 USA  
Main Tel: (631) 435-1110  
Main Fax: (631) 435-1824  
Support Team Fax: (631) 435-3388  
[www.centrasemi.com](http://www.centrasemi.com)

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